

# SM20MT05C thru SM20MT24C

# BIDIRECTIONAL MONOLITHIC TVS DIODE ARRAY

#### **APPLICATIONS**

- RS-232, RS-422 & RS-423 Data Lines
- Industrial & Instrumentation Equipment
- Board Level Interface Protection
- I/O Port Protection

## **FEATURES**

- IEC 1000-4-2, -4 & -5 Industry Requirements
- 1,500 Watts Peak Pulse Power Dissipation per Line (8/20 μs)
- Low Inductance, Crosstalk & Low Overshoot Voltage
- ESD Protection > 40 kilovolts
- Available in 4 Voltage Types Ranging from 5.0V to 24V
- Up to 9 Bidirectional Data Lines of Protection
- Externally Low Clamping Voltage
- Bidirectional Monolithic Design
- UL 94V-0 Flammability Classification

## **DESCRIPTION**

The SM20MTxxC family is a series of bidirectional, monolithic, silicon transient voltage suppressor (TVS) arrays designed to provide protection against ESD and EFT. The SM20MTxxC surface mount series is designed to protect up to nine (9) bidirectional I/O ports against IEC 1000-4-2, -4, -5 requirements and specifically for RS-232 and RS-423. This device provides a low clamping voltage at a high surge current of 40 Amps based on an 8/20 waveshape and 1,500 Watts per line peak pulse power ( $P_{\rm PP}$ ) rating for an 8/20  $\mu s$  waveshape. When subjected to fast rise time transient events such as ESD and EFT, the SM20MTxxC series yields a low overshoot voltage with a minimum lead inductance.

The SM20MTxxC series has a low inductance package consisting of a 4-point structure with isolated input to output pins that eliminates overshoot voltage due to external lead attachments and perturbations caused by parasitic inductances. This unique internal design provides protection against very high (di/dt) rates such as ESD. Considered an in-line protection device, the monolithic chip design and internal construction ensures reliable protection against the very fast transient overvoltage ESD events, such as Human Body Model (HBM), Machine Model (MM), and Charge Device Model (CDM).

MAXIMUM RATINGS					
P <sub>PP</sub> @ 25°C (See Figure 1)	1,500 Watts per Line, 8/20 μs Waveshape				
Operating & Storage Temperature	-55° to +150°C				
Repetition Rate (Duty Cycle)	0.01%				
t <sub>Clamping</sub> (0 Volts to V <sub>(BR)</sub> Min.)	Bidirectional: < 10 x 10 <sup>-9</sup> seconds				
MECHANICAL CHARACTERISTICS					
Package	Molded SO-20L Wide Body Surface Mount Package				
Packaging	Tube or 24mm Tape per EIA 481				
Approximate Weight	0.5 grams				
Device Markings	Logo & Part Number				
Miscellaneous	Pin No. 1 Indicated by Dot on Top of Package				

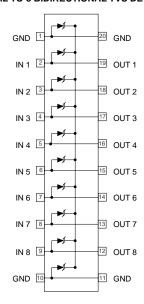
## **IEC 1000-4 COMPATIBLE**



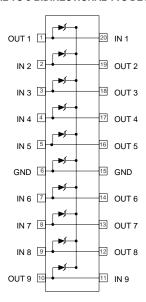
# **SO-20L PACKAGE**

## **CIRCUIT DIAGRAMS**

#### **EQUAL TO 8 BIDIRECTIONAL TVS DEVICES**

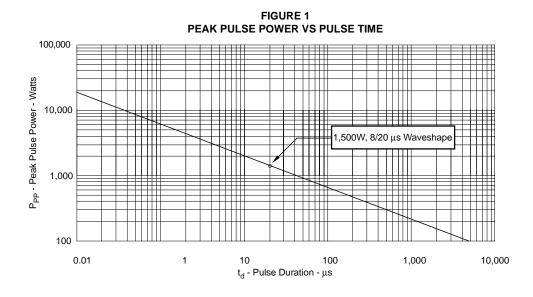


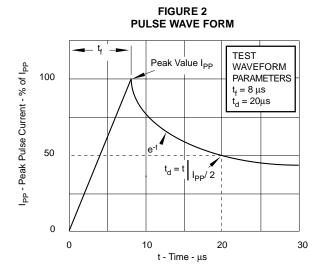
#### **EQUAL TO 9 BIDIRECTIONAL TVS DEVICES**

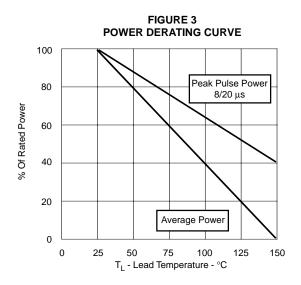


ELECTRICAL CHARACTERISTICS @ 25° C Ambient Temperature									
PROTEK PART NUMBER (See Note 1)	RATED STAND-OFF VOLTAGE V <sub>WM</sub> VOLTS	MINIMUM BREAKDOWN VOLTAGE @ 1 mA V <sub>(BR)</sub> VOLTS	MAXIMUM CLAMPING VOLTAGE (See Fig. 2) @ I <sub>P</sub> = 10 A V <sub>C</sub> VOLTS	MAXIMUM CLAMPING VOLTAGE (See Fig. 2) @ I <sub>P</sub> = 25 A V <sub>C</sub> VOLTS	MAXIMUM LEAKAGE CURRENT @ V <sub>WM</sub> I <sub>D</sub> µA	TYPICAL CAPACITANCE  @ 1 MHz, V <sub>WM</sub> C pF			
SM20MT05C SM20MT08C SM20MT15C SM20MT24C	5.0 8.0 15.0 24.0	6.5 10 18 25	9.5 13 23 31	11 17 26 36	50 10 4 4	700 360 250 140			

Note 1: These devices are bidirectional only. Electrical characteristics apply in both directions. The monolithic TVS array is based on 10 unidirectional P/N junctions with a common cathode and can be configured to offer 8 to 9 bidirectional data lines of protection. The inputs and outputs are symmetrical and can be reversed for specific application layout requirements.

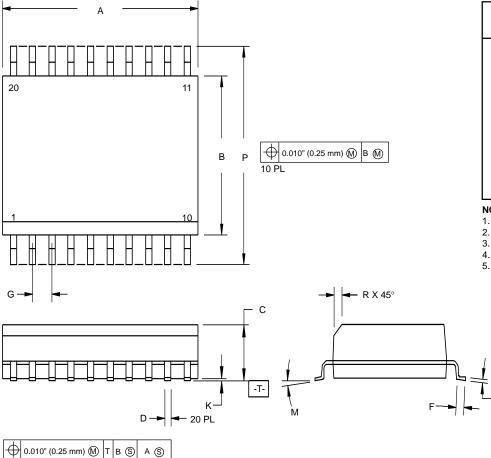






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# **SO-20L PACKAGE OUTLINE**



# **SO-20L PACKAGE DIMENSIONS** (WIDE BODY)

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	12.65	12.95	0.499	0.510	
В	7.40	7.60	0.292	0.299	
С	2.35	2.65	0.093	0.104	
D	0.35	0.49	0.014	0.019	
F	0.50	0.90	0.020	0.035	
G	1.27 BSC	1.27 BSC	0.05 BSC	0.05 BSC	
J	0.25	0.32	0.010	0.012	
K	0.10	0.25	0.004	0.009	
М	0°	7°	0°	7°	
Р	10.05	10.55	0.395	0.415	
	0.25	0.75	0.010	0.029	

#### NOTES:

- 1. T = Seating Plane
- Dimension "A" is Datum
   Dimension "A" and "B" do not include mold protusion.
- 4. Maximum mold protrusion is 0.15" (0.006 mm).
- 5. Dimensioning and tolerances per ANSI Y14.5M, 1982.

